

ASM3P1819N

rev 0.3

Low Power Mobile VGA EMI Reduction IC

Features

- FCC approved method of EMI attenuation
- Provides up to 15dB EMI reduction
- Generates a low EMI spread spectrum clock and a non-spread Reference Clock of the input frequency
- Optimized for frequency range from 20MHz to 40MHz
- Internal loop filter minimizes external components
 and board space
- Down Spread Deviation: -1.25%
- Low inherent Cycle-to-Cycle jitter
- 3.3V Operating Voltage
- CMOS/TTL compatible inputs and outputs
- Low power CMOS design
- Supports notebook VGA and other LCD timing controller applications
- Power Down function for mobile application
- Products are available for industrial temperature range.
- Available in 8 pin SOIC and TSSOP Packages

Functional Description

The ASM3P1819N is a versatile spread spectrum frequency modulator designed specifically for a wide range of input clock frequencies from 20 to 40MHz. The ASM3P1819N can generate an EMI reduced clock from crystal, ceramic resonator, or system clock.

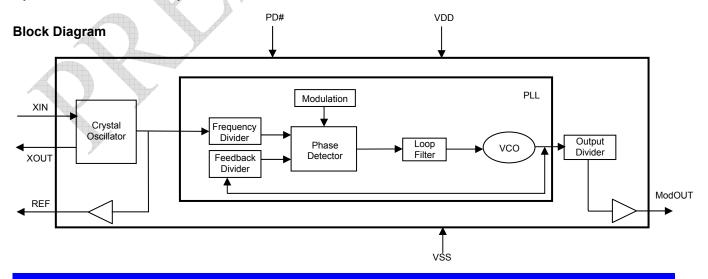
The ASM3P1819N reduces electromagnetic interference (EMI) at the clock source, allowing a system wide EMI reduction for all the down stream clocks and data dependent signals. The ASM3P1819N allows significant system cost savings by reducing the number of circuit board layers, ferrite beads, shielding, and other passive components that are traditionally required to pass EMI regulations.

The ASM3P1819N modulates the output of a single PLL in order to "spread" the bandwidth of a synthesized clock, thereby decreasing the peak amplitude of its harmonics. This result in significantly lower system EMI compared to the typical narrow band signal produced by oscillators and most clock generators.

Lowering EMI by increasing a signal's bandwidth is called "spread spectrum clock generation". The ASM3P1819N uses the most efficient and optimized modulation profile approved by the FCC and is implemented by using a proprietary all digital method

Applications

The ASM3P1819N is targeted towards EMI management for memory and LVDS interfaces in mobile graphic chipsets and high-speed digital applications such as PC peripheral devices, consumer electronics and embedded controller system.



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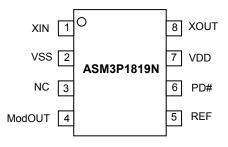


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Pin Configuration



Pin Description

| - | | | Ville Automatica A |
|------|----------|------|--|
| Pin# | Pin Name | Туре | Description |
| 1 | XIN | I | Connect to externally generated Clock signal or Crystal. |
| 2 | VSS | Р | Ground Connection. Connect to system ground. |
| 3 | NC | - | No Connect. |
| 4 | ModOUT | 0 | Spread spectrum clock output. |
| 5 | REF | 0 | Non-modulated Reference clock output of the input frequency. |
| 6 | PD# | I | Power down control pin. Pull LOW to enable Power-Down mode. This pin has an internal pull-up resistor. |
| 7 | VDD | Р | Connect to +3.3V. |
| 8 | XOUT | - 1 | Connect to crystal. No connect if externally generated clock signal is used. |

Absolute Maximum Ratings

| Parameter | Rating | Unit |
|--|--|--|
| Voltage on any pin with respect to Ground | -0.5 to +4.6 | V |
| Storage temperature | -65 to +125 | °C |
| Operating temperature | -40 to +85 | °C |
| Max. Soldering Temperature (10 sec) | 260 | °C |
| Junction Temperature | 150 | °C |
| Static Discharge Voltage (As per JEDEC STD22- A114-B) | 2 | κv |
| | Voltage on any pin with respect to Ground Storage temperature Operating temperature Max. Soldering Temperature (10 sec) Junction Temperature Static Discharge Voltage | Voltage on any pin with respect to Ground-0.5 to +4.6Storage temperature-65 to +125Operating temperature-40 to +85Max. Soldering Temperature (10 sec)260Junction Temperature150Static Discharge Voltage2 |

Output Frequency and Modulation Rate

| Input Frequency Range | Output Frequency Range | Modulation Rate | Spread Deviation | |
|-----------------------|------------------------|-----------------------|------------------|--|
| (MHz) | (MHz) | | (%) | |
| 20 to 40 | 20 to 40 | Input Frequency / 512 | -1.25 | |



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DC Electrical Characteristics

(Test condition: All parameters are measured at room temperature (+25°C) unless otherwise stated)

| Symbol | Parameter | Min | Тур | Мах | Unit |
|------------------|---|------------------------------|------|-------------------------------|------|
| V _{IL} | Input Low voltage | VSS – 0.3 | - | 0.8 | V |
| V _{IH} | Input High voltage | 2.0 | - | VDD + 0.3 | V |
| IIL | Input Low current | - | - | -20.0 | μA |
| I _{IH} | Input High current | - | - 4 | 1.0 | μA |
| I _{XOL} | X_{OUT} Output low current @ 0.4V, VDD = 3.3V | - | 3 | | mA |
| I _{XOH} | X _{OUT} Output high current @ 2.5V, VDD = 3.3V | - | 3 | -) | mA |
| V _{OL} | Output Low voltage VDD = 3.3V, I _{OL} = 20mA | - | | 0.4 | V |
| V _{OH} | Output High voltage VDD = 3.3V, I _{OH} = 20mA | 2.5 | | - | V |
| I _{CC} | Dynamic Supply current 3.3V and 10pF probe loading | 7.1 f _{IN - min} | | 26.9 f _{IN - max} | mA |
| I _{DD} | Static Supply current | / | 4.5 | - | mA |
| VDD | Operating Voltage | \mathbf{Y} | 3.3 | - | V |
| t _{ON} | Power up time (First locked clock cycle after power up) | - | 0.18 | - | mS |
| Z _{OUT} | Clock Output impedance | - | 50 | - | Ω |

AC Electrical Characteristics

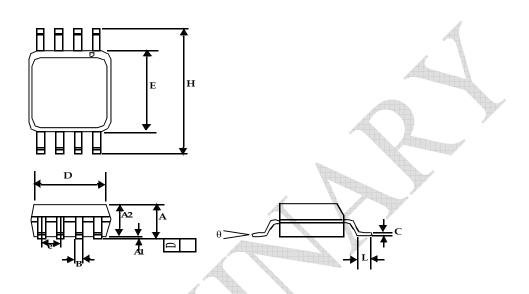
| Frequency It Frequency | 20 20 | - | 40 | MHz |
|---|---|--|--|---|
| | 20 | | | 1 |
| | | - | 40 | MHz |
| ut Rise time sured from 0.8V to 2.0V) | - | 0.69 | - | nS |
| ut Fall time sured from 2.0V to 0.8V) | - | 0.66 | - | nS |
| (Cycle to Cycle) | -200 | - | 200 | pS |
| ut Duty cycle | 45 | 50 | 55 | % |
| | it Fall time sured from 2.0V to 0.8V) (Cycle to Cycle) | sured from 0.8V to 2.0V) - it Fall time - sured from 2.0V to 0.8V) - (Cycle to Cycle) -200 it Duty cycle 45 | sured from 0.8V to 2.0V)-0.66it Fall time sured from 2.0V to 0.8V)-0.66(Cycle to Cycle)-200-it Duty cycle4550 | sured from 0.8V to 2.0V) - 0.66 - it Fall time sured from 2.0V to 0.8V) - 0.66 - (Cycle to Cycle) -200 - 200 it Duty cycle 45 50 55 |



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8-Pin (150-mil) SOIC Package



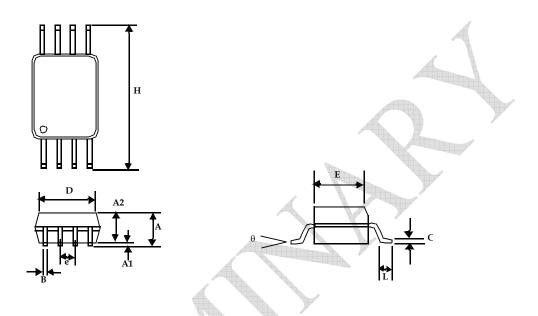
| | Dimensions | | | | |
|--------|------------|-------|-------------|------|--|
| Symbol | Inc | hes | Millimeters | | |
| | Min | Мах | Min | Мах | |
| A1 | 0.004 | 0.010 | 0.10 | 0.25 | |
| A | 0.053 | 0.069 | 1.35 | 1.75 | |
| A2 | 0.049 | 0.059 | 1.25 | 1.50 | |
| В | 0.012 | 0.020 | 0.31 | 0.51 | |
| С | 0.007 | 0.010 | 0.18 | 0.25 | |
| D | 0.193 BSC | | 4.90 BSC | | |
| E | 0.154 BSC | | 3.91 BSC | | |
| е | 0.050 BSC | | 1.27 BSC | | |
| Н | 0.236 BSC | | 6.00 BSC | | |
| L | 0.016 | 0.050 | 0.41 | 1.27 | |
| θ | 0° | 8° | 0° | 8° | |

Note: Controlling dimensions are millimeters SOIC – 0.074 grams unit weight



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8-lead Thin Shrunk Small Outline Package (4.40-MM Body)



| | Dimensions | | | | |
|----------------|------------|-------|-------------|------|--|
| Symbol | Inc | hes | Millimeters | | |
| | Min | Max | Min | Max | |
| А | | 0.043 | | 1.10 | |
| A1 | 0.002 | 0.006 | 0.05 | 0.15 | |
| A2 | 0.033 | 0.037 | 0.85 | 0.95 | |
| В | 0.008 | 0.012 | 0.19 | 0.30 | |
| с | 0.004 | 0.008 | 0.09 | 0.20 | |
| D | 0.114 | 0.122 | 2.90 | 3.10 | |
| E | 0.169 | 0.177 | 4.30 | 4.50 | |
| e | 0.026 BSC | | 0.65 BSC | | |
| [▶] H | 0.252 BSC | | 6.40 BSC | | |
| L | 0.020 | 0.028 | 0.50 | 0.70 | |
| θ | 0° | 8° | 0° | 8° | |

Note: Controlling dimensions are millimeters TSSOP – 0.0325 grams unit weight



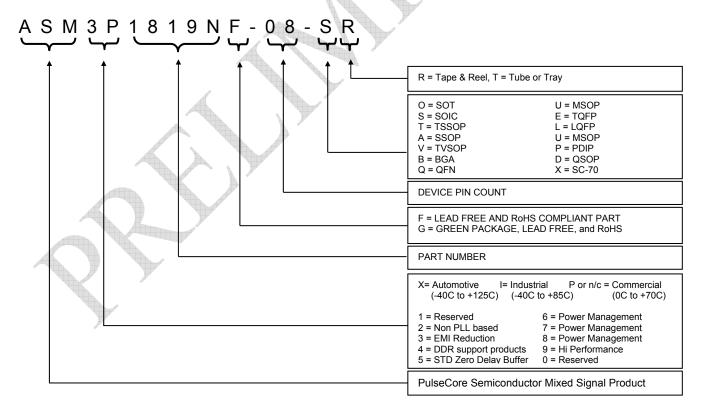
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Ordering Information

| Part Number | Marking | Package Type | Temperature |
|-------------------|----------|-------------------------------------|-------------|
| ASM3P1819NF-08-ST | 3P1819NF | 8-Pin SOIC, Tube, Pb Free | Commercial |
| ASM3P1819NF-08-SR | 3P1819NF | 8-Pin SOIC, Tape and Reel, Pb Free | Commercial |
| ASM3P1819NG-08-ST | 3P1819NG | 8-Pin SOIC, Tube, Green | Commercial |
| ASM3P1819NG-08-SR | 3P1819NG | 8-Pin SOIC, Tape and Reel, Green | Commercial |
| ASM3I1819NF-08-ST | 3I1819NF | 8-Pin SOIC, Tube, Pb Free | Industrial |
| ASM3I1819NF-08-SR | 3I1819NF | 8-Pin SOIC, Tape and Reel, Pb Free | Industrial |
| ASM3I1819NG-08-ST | 3I1819NG | 8-Pin SOIC, Tube, Green | Industrial |
| ASM3I1819NG-08-SR | 3I1819NG | 8-Pin SOIC, Tape and Reel, Green | Industrial |
| ASM3P1819NF-08-TT | 3P1819NF | 8-Pin TSSOP, Tube, Pb Free | Commercial |
| ASM3P1819NF-08-TR | 3P1819NF | 8-Pin TSSOP, Tape and Reel, Pb Free | Commercial |
| ASM3P1819NG-08-TT | 3P1819NG | 8-Pin TSSOP, Tube, Green | Commercial |
| ASM3P1819NG-08-TR | 3P1819NG | 8-Pin TSSOP, Tape and Reel, Green | Commercial |
| ASM3I1819NF-08-TT | 3I1819NF | 8-Pin TSSOP, Tube, Pb Free | Industrial |
| ASM3I1819NF-08-TR | 3I1819NF | 8-Pin TSSOP, Tape and Reel, Pb Free | Industrial |
| ASM3I1819NG-08-TT | 3I1819NG | 8-Pin TSSOP, Tube, Green | Industrial |
| ASM3I1819NG-08-TR | 3I1819NG | 8-Pin TSSOP, Tape and Reel, Green | Industrial |

Device Ordering Information



Licensed under US patent #5,488,627, #6,646,463 and #5,631,920



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Note: This product utilizes US Patent #6,646,463 Impedance Emulator Patent issued to PulseCore Semiconductor, dated 11-11-2003

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